NSN 5961-00-783-8188

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-783-8188 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Overall Diameter:** 0.140 inches **Mounting Method: Terminal Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 40.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 180.00 milliamperes source cutoff current and 60.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 80.0 milliwatts small-signal input power, common-collector nanoamperes **Test Data Document:** 06481-900120-74 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: